NSN 5961-01-258-4755

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View Online at https://aerobasegroup.com/nsn/5961-01-258-4755

Inclosure Material:

Metal

Overall Length:

1.573 inches

Terminal Length:

0.312 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal and unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 400.0 breakdown voltage, collector-to-emitter,

base open and 20.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

10.00 amperes all primaries

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: npn

Precious Material And Location:

Terminal surfaces gold

Precious Material:

Gold

Test Data Document:

03640-6135167 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

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Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0

